

MS2341

MS2341 Information

Heisener.com	Part Number Manufacturer Category Description Package	MS2341 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF BIPO 87.5W 2.6A M115 M115	
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

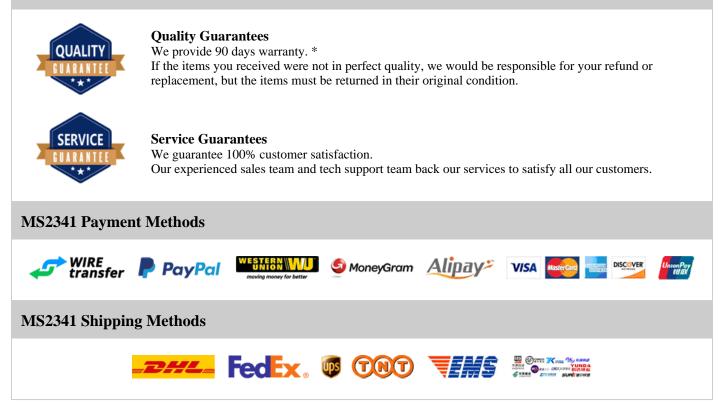
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MS2341 Specifications

Manufacturer Part Number	MS2341
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	M115
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	65V
Frequency - Transition	1.025GHz ~ 1.15GHz
Noise Figure (dB Typ @ f)	-
Gain	9dB
Power - Max	87.5W
DC Current Gain (hFE) (Min) @ Ic, Vce	-
Current - Collector (Ic) (Max)	2.6A
Operating Temperature	200°C (TJ)
Mounting Type	Chassis Mount
Package / Case	M115
Supplier Device Package	M115
	Report errors?

MS2341 Guarantees



If you have any question about MS2341, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com